

CURRENT-LIMITED POWER-DISTRIBUTION SWITCH

Check for Samples: [TPS2041B-EP](#)

FEATURES

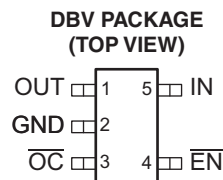
- 70-mΩ High-Side MOSFET
- 500-mA Continuous Current
- Thermal and Short-Circuit Protection
- Current Limit:
0.45 A (Min), 1.55 A (Max)
- Operating Range: 2.7 V to 5.5 V
- 0.6-ms Typical Rise Time
- Undervoltage Lockout
- Deglitched Fault Report (\overline{OC})
- No \overline{OC} Glitch During Power Up
- Maximum Standby Supply Current: 1 μ A
- Bidirectional Switch
- ESD Protection Level Per AEC-Q100 Classification
- UL Recognized, File Number E169910

APPLICATIONS

- Heavy Capacitive Loads
- Short-Circuit Protection

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military ($-55^{\circ}\text{C}/125^{\circ}\text{C}$) Temperature Range
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability



DESCRIPTION

The TPS2041B power-distribution switch is intended for applications where heavy capacitive loads and short circuits are likely to be encountered. This device incorporates 70-mΩ N-channel MOSFET power switches for power-distribution systems that require multiple power switches in a single package. Each switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent (\overline{OC}) logic output low. When continuous heavy overloads and short circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures that the switch remains off until valid input voltage is present. This power-distribution switch is designed to set current limit at 1 A (typ).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

T _J	ENABLE	NO. OF SWITCHES	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	VID NUMBER
–55°C to 125°C	Active low	Single	SOT-23 – DBV	TPS2041BMDVBTEP	PXAM	V62/11620-01XE

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

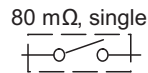


Figure 1. TPS2041B Switch at 500 mA

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range unless otherwise noted

V _{I(IN)}	Input voltage range (IN) ⁽²⁾	–0.3 V to 6 V
V _{O(OUT)}	Output voltage range (OUT) ⁽²⁾	–0.3 V to 6 V
V _{I(EN)}	Input voltage range ($\overline{\text{EN}}$)	–0.3 V to 6 V
V _{I(OC)}	Voltage range ($\overline{\text{OC}}$)	–0.3 V to 6 V
I _{O(OUT)}	Continuous output current	Internally limited
	Continuous power dissipation at 125°C	182 mW
θ _{JC}	Thermal resistance, junction-to-case	55°C/W
T _J	Operating virtual-junction temperature range	–55°C to 135°C
T _{stg}	Storage temperature range	–65°C to 150°C
	Lead temperature, soldering	1,6 mm (1/16 in) from case for 10 s 260°C
Electrostatic discharge (ESD) protection	Human-Body Model (HBM) (H2)	2500 V
	Machine Model (MM) (M0)	50 V
	Charged-Device Model (CDM) (C5)	1500 V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to GND.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{I(IN)}	Input voltage (IN)	2.7	5.5	V
V _{I(EN)}	Input voltage ($\overline{\text{EN}}$)	0	5.5	V
I _{O(OUT)}	Continuous output current (OUT)	0	500	mA
T _J	Operating virtual-junction temperature	–55	125	°C

ELECTRICAL CHARACTERISTICS

over recommended operating junction temperature range, $V_{I(IN)} = 5.5\text{ V}$, $I_O = 0.5\text{ A}$, $V_{I(\overline{EN})} = 0\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Power Switch							
r _{DS(on)}	Static drain-source on-state resistance, 5-V or 3.3-V operation	V _{I(IN)} = 5 V or 3.3 V, I _O = 0.5 A	−55°C ≤ T _J ≤ 125°C	70	135		mΩ
	Static drain-source on-state resistance, 2.7-V operation	V _{I(IN)} = 2.7 V, I _O = 0.5 A	−55°C ≤ T _J ≤ 125°C	75	150		
t _r	Rise time, output	V _{I(IN)} = 5.5 V	C _L = 1 μF, R _L = 10 Ω	T _J = 25°C	0.6		ms
		V _{I(IN)} = 2.7 V			0.4		
t _f	Fall time, output	V _{I(IN)} = 5.5 V			0.2		
		V _{I(IN)} = 2.7 V			0.2		
Enable Input ($\overline{\text{EN}}$)							
V _{IH}	High-level input voltage	2.7 V ≤ V _{I(IN)} ≤ 5.5 V		2			V
V _{IL}	Low-level input voltage	2.7 V ≤ V _{I(IN)} ≤ 5.5 V			0.8		V
I _I	Input current	V _{I($\overline{\text{EN}}$)} = 0 V or 5.5 V		−1		1	μA
t _{on}	Turn-on time	C _L = 100 μF, R _L = 10 Ω			3		ms
t _{off}	Turn-off time	C _L = 100 μF, R _L = 10 Ω			6		ms
Current Limit							
I _{OS}	Short-circuit output current	V _{I(IN)} = 5 V, OUT connected to GND, device enabled into short-circuit	T _J = 25°C	0.65	1	1.3	A
			−55°C ≤ T _J ≤ 125°C	0.45	1	1.55	
Supply Current							
Supply current, low-level output	No load on OUT, V _{I($\overline{\text{EN}}$)} = 5.5 V or V _{I(EN)} = 0 V	T _J = 25°C	0.5	1		μA	
		−55°C ≤ T _J ≤ 125°C	0.5	5			
Supply current, high-level output	No load on OUT, V _{I($\overline{\text{EN}}$)} = 0 V or V _{I(EN)} = 5.5 V	T _J = 25°C	43	60		μA	
		−55°C ≤ T _J ≤ 125°C	43	70			
Leakage current	OUT connected to ground, V _{I($\overline{\text{EN}}$)} = 5.5 V or V _{I(EN)} = 0 V	−55°C ≤ T _J ≤ 125°C	1			μA	
Reverse leakage current	V _{I(OUT)} = 5.5 V, IN = ground	T _J = 25°C	0			μA	
Undervoltage Lockout							
Low-level input voltage, IN				2		2.5	V
Hysteresis, IN		T _J = 25°C		75			mV
$\overline{\text{OC}}$							
Output low voltage, V _{OL(OC)}		I _{O($\overline{\text{OC}}$)} = 5 mA			0.4		V
Off-state current		V _{O($\overline{\text{OC}}$)} = 5 V or 3.3 V				1	μA
$\overline{\text{OC}}$ deglitch		$\overline{\text{OC}}$ assertion or deassertion		3	8	16	ms
Thermal Shutdown ⁽²⁾							
Thermal shutdown threshold				135			°C
Recovery from thermal shutdown				125			°C
Hysteresis					10		°C

(1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be accounted for separately.

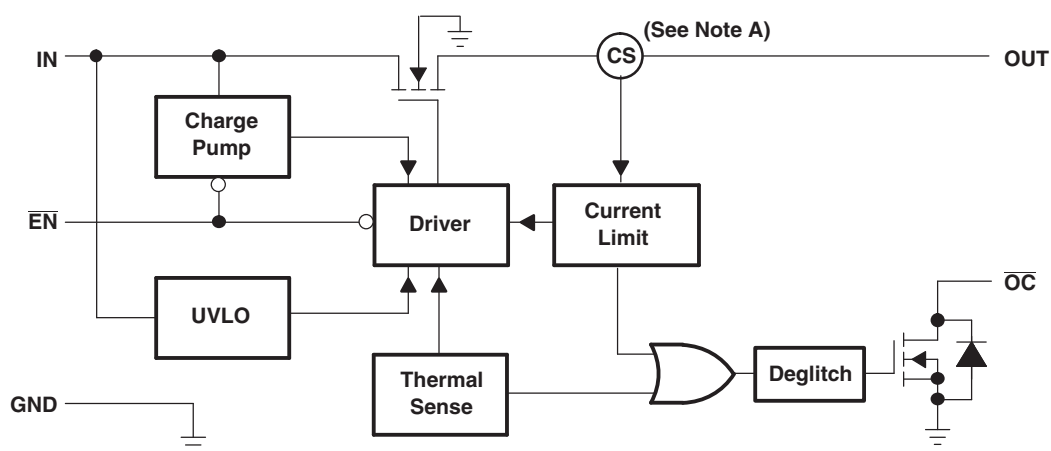
(2) The thermal shutdown only reacts under overcurrent conditions.

DEVICE INFORMATION

Terminal Functions

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
$\overline{\text{EN}}$	4	I	Enable input, logic low turns on power switch
GND	2		Ground
IN	5	I	Input voltage
$\overline{\text{OC}}$	3	O	Overcurrent, open-drain output, active low
OUT	1	O	Power-switch output

Functional Block Diagram



A. CS = Current sense

PARAMETER MEASUREMENT INFORMATION

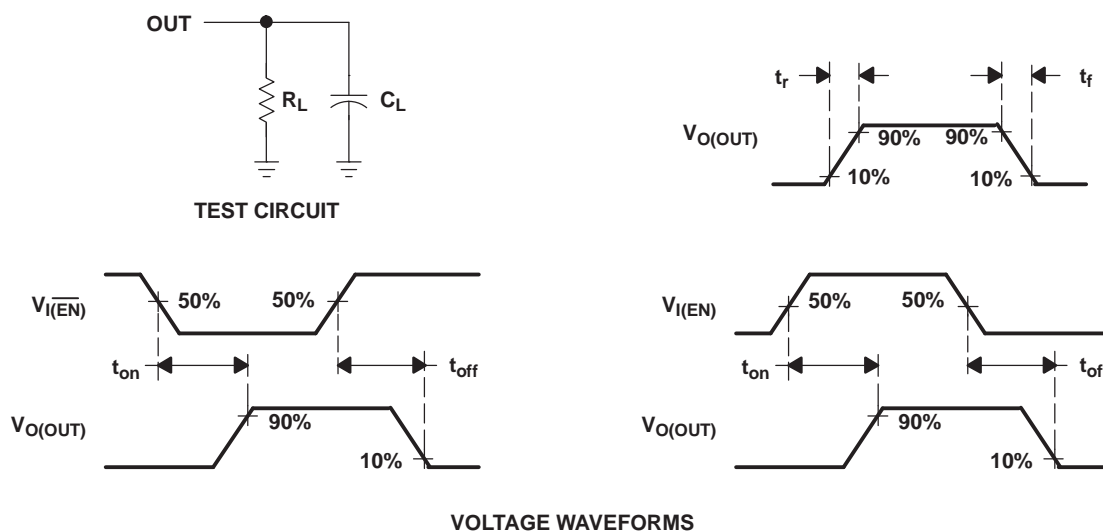


Figure 2. Test Circuit and Voltage Waveforms

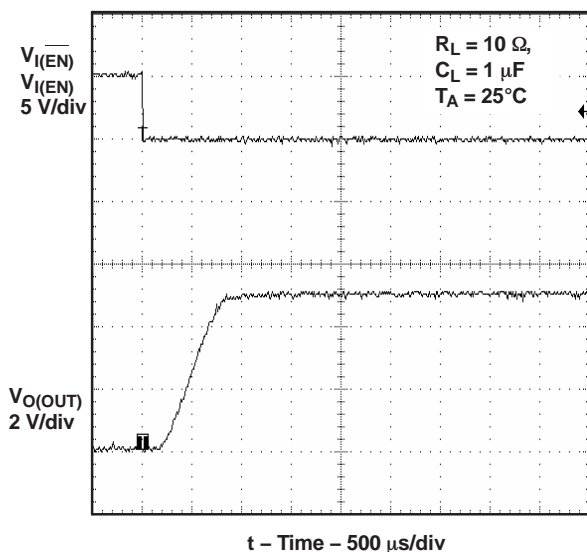


Figure 3. Turn-On Delay and Rise Time With 1- μF Load

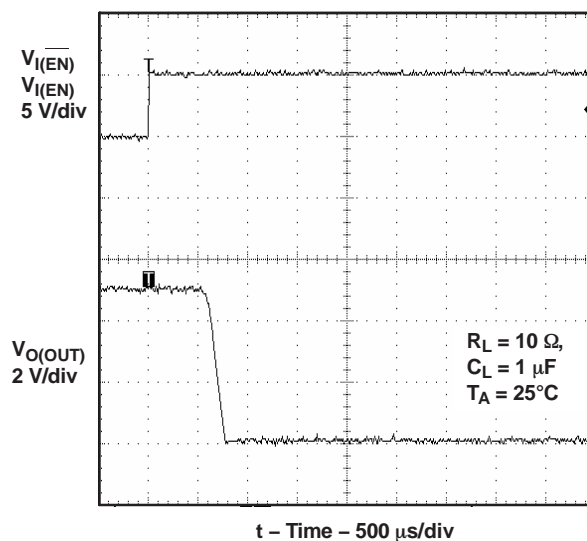
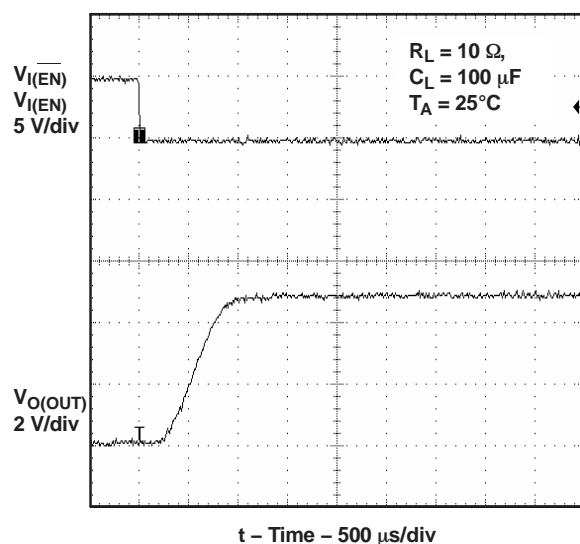
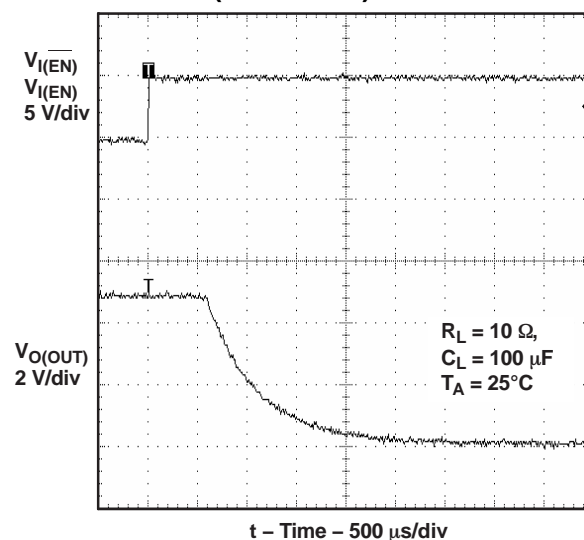
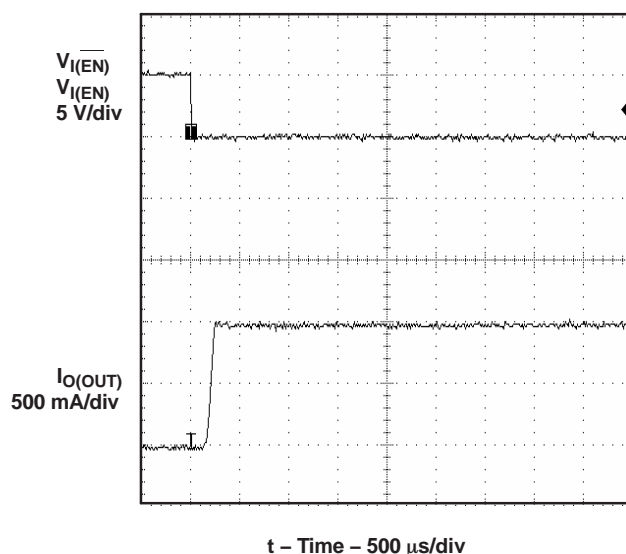
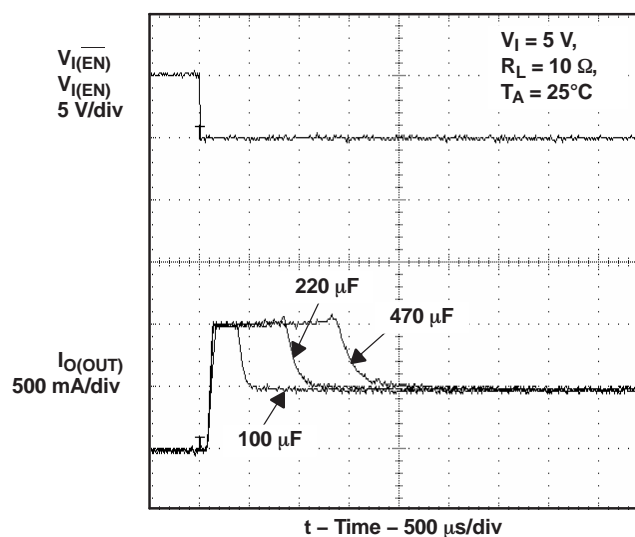


Figure 4. Turn-Off Delay and Fall Time With 1- μF Load

PARAMETER MEASUREMENT INFORMATION (continued)
Figure 5. Turn-On Delay and Rise Time With 100- μF Load

Figure 6. Turn-Off Delay and Fall Time With 100- μF Load

Figure 7. Short-Circuit Current, Device Enabled Into Short

Figure 8. Inrush Current With Different Load Capacitance

PARAMETER MEASUREMENT INFORMATION (continued)

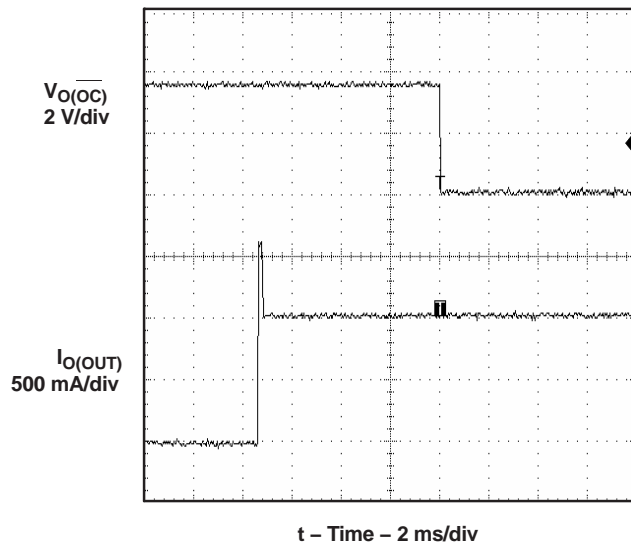


Figure 9. 3- Ω Load Connected to Enabled Device

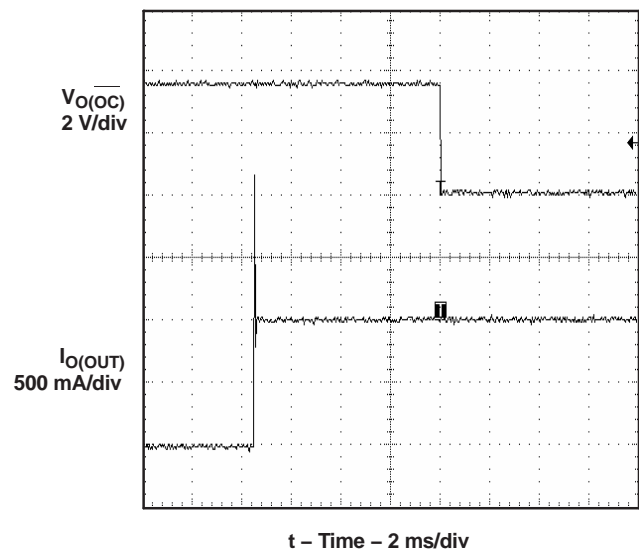


Figure 10. 2- Ω Load Connected to Enabled Device

TYPICAL CHARACTERISTICS

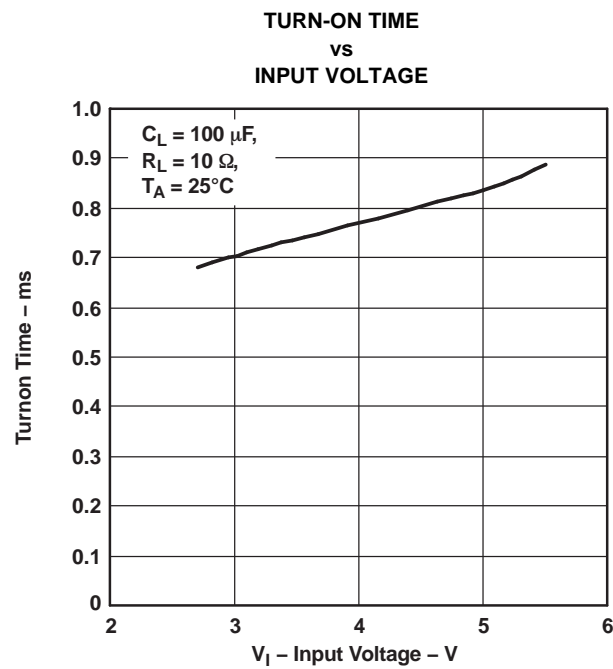


Figure 11.

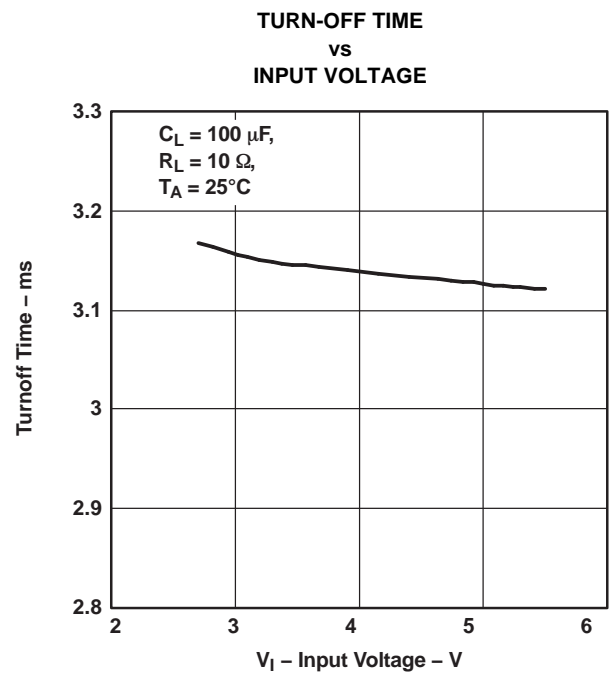


Figure 12.

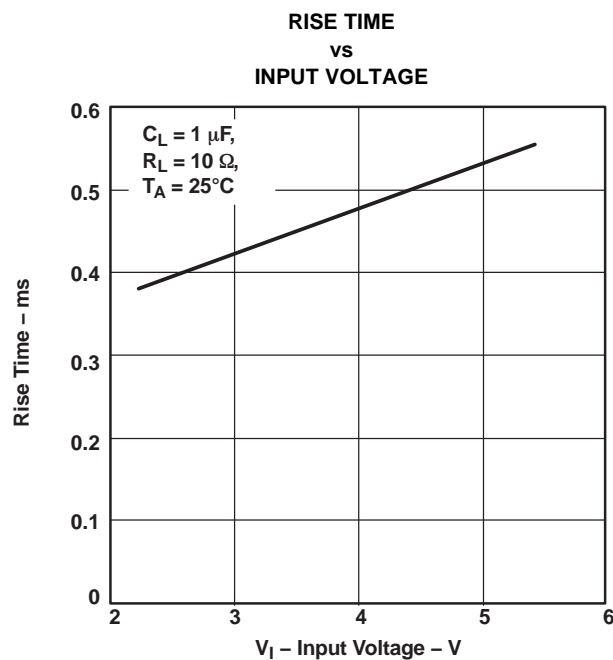


Figure 13.

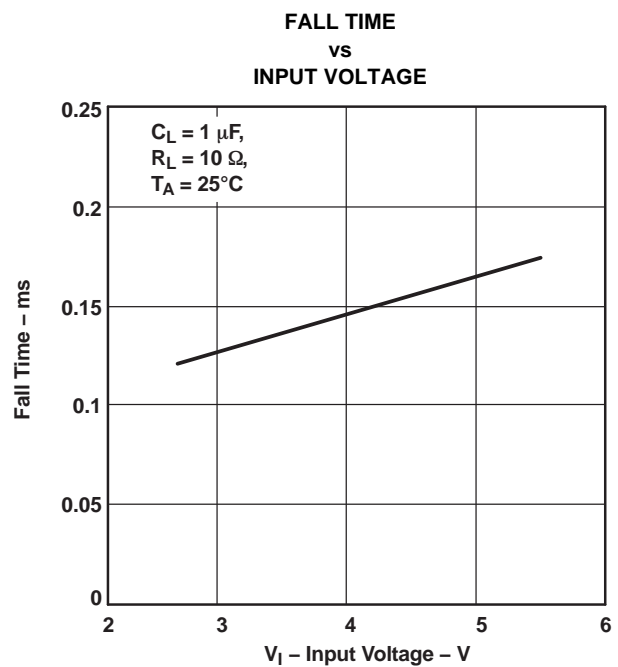


Figure 14.

TYPICAL CHARACTERISTICS (continued)

SUPPLY CURRENT, OUTPUT ENABLED
vs
JUNCTION TEMPERATURE

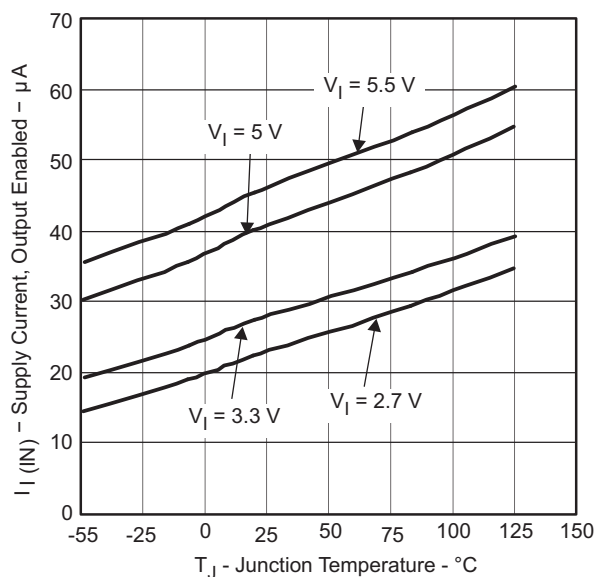


Figure 15.

SUPPLY CURRENT, OUTPUT DISABLED
vs
JUNCTION TEMPERATURE

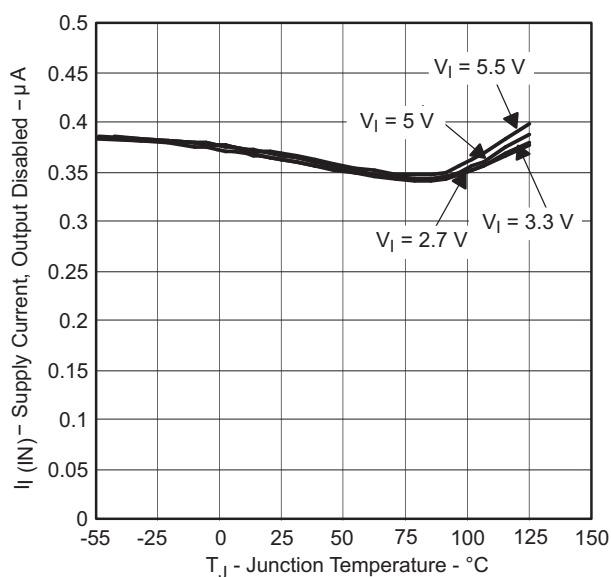


Figure 16.

STATIC DRAIN-SOURCE ON-STATE RESISTANCE
vs
JUNCTION TEMPERATURE

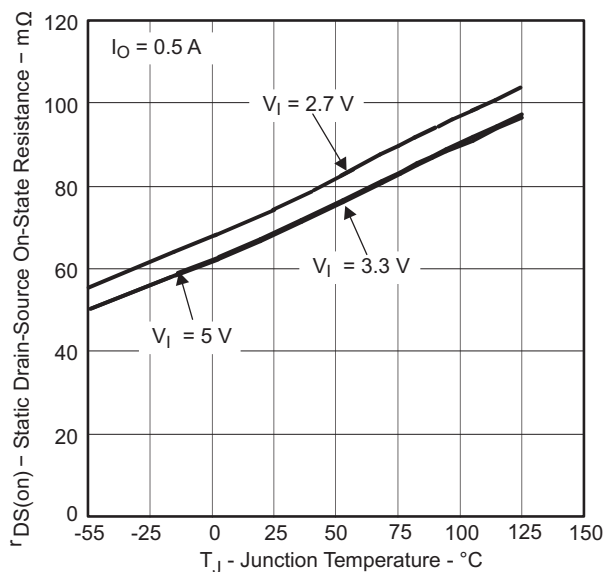


Figure 17.

SHORT-CIRCUIT OUTPUT CURRENT
vs
JUNCTION TEMPERATURE

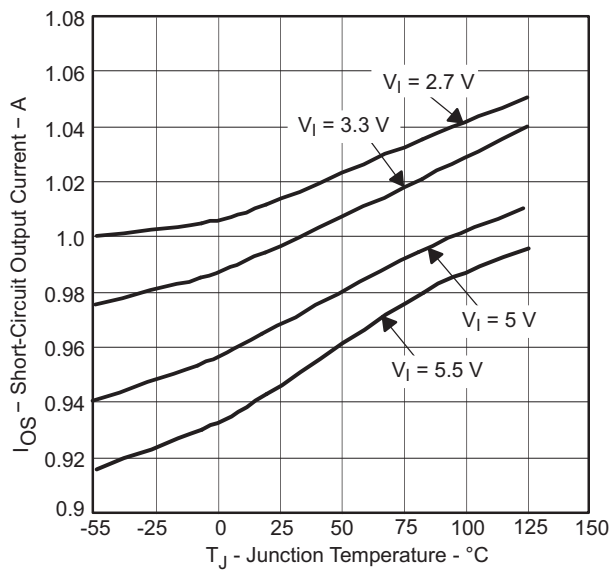


Figure 18.

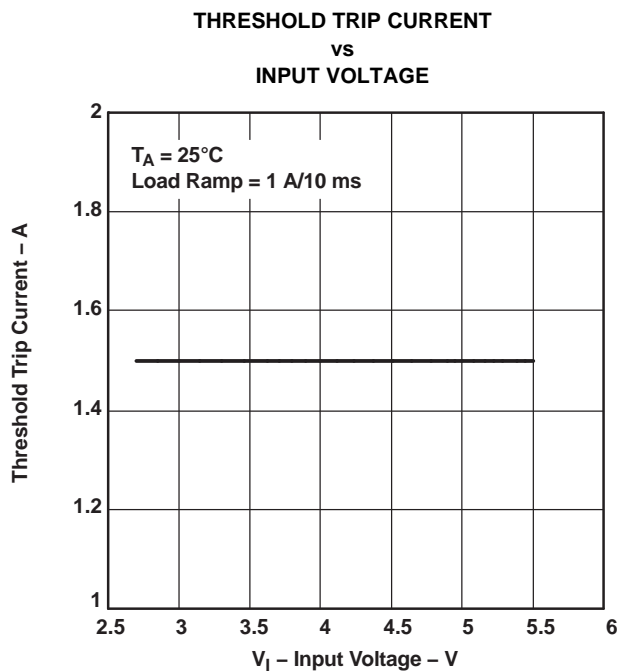
TYPICAL CHARACTERISTICS (continued)

Figure 19.

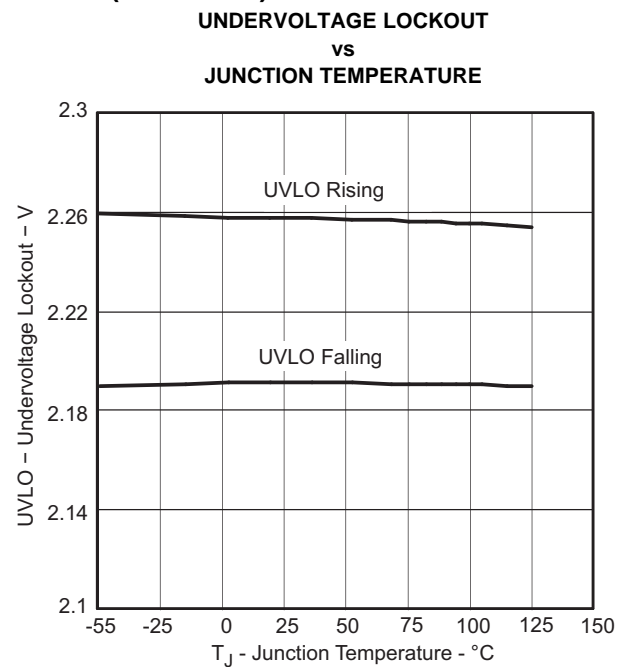


Figure 20.

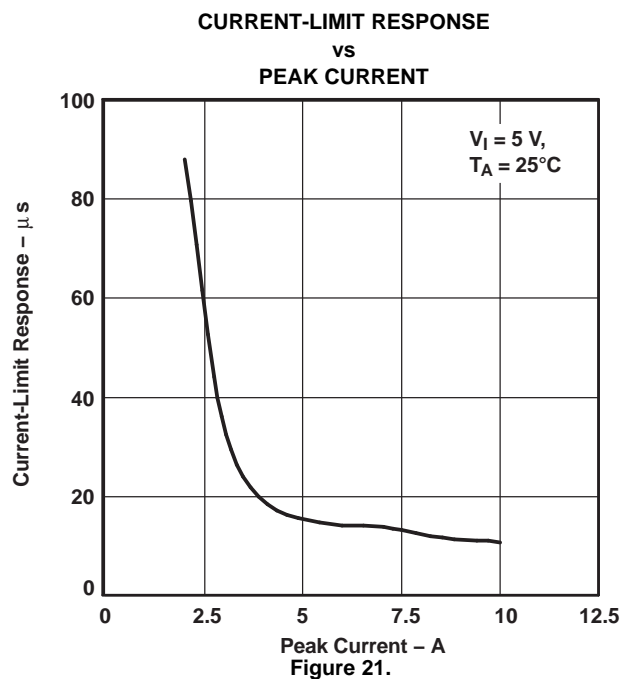


Figure 21.

APPLICATION INFORMATION

Power-Supply Considerations

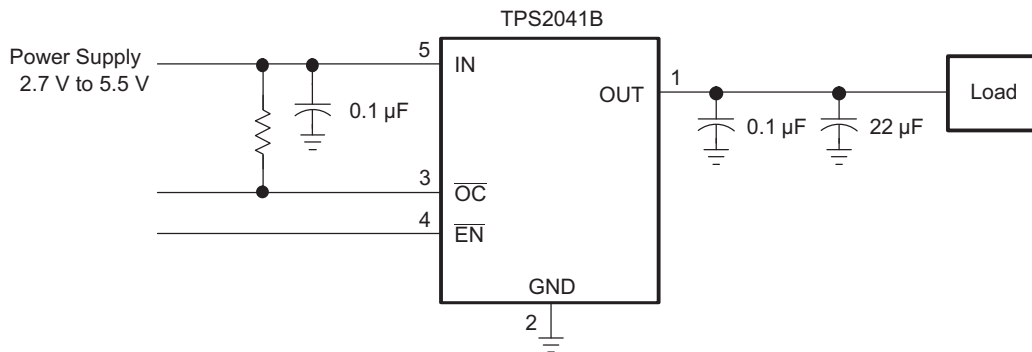


Figure 22. Typical Application

A 0.01- μ F to 0.1- μ F ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01- μ F to 0.1- μ F ceramic capacitor improves the immunity of the device to short-circuit transients.

Overcurrent

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before $V_{I(IN)}$ has been applied (see Figure 15). The TPS2041B senses the short and immediately switches into a constant-current output.

In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, high currents may flow for a short period of time before the current-limit circuit can react. After the current-limit circuit has tripped (reached the overcurrent trip threshold), the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded (see Figure 16). The TPS2041B is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

\overline{OC} Response

The \overline{OC} open-drain output is asserted (active low) when an overcurrent or overtemperature shutdown condition is encountered after a 10-ms deglitch timeout. The output remains asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause a momentary overcurrent condition; however, no false reporting on \overline{OC} occurs due to the 10-ms deglitch circuit. The TPS2041B is designed to eliminate false overcurrent reporting. The internal overcurrent deglitch eliminates the need for external components to remove unwanted pulses. \overline{OC} is not deglitched when the switch is turned off due to an overtemperature shutdown.

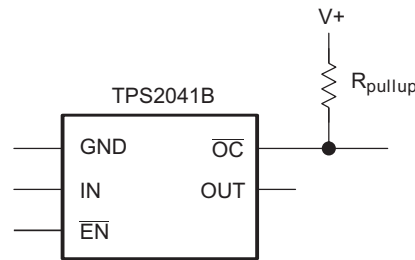


Figure 23. Typical Circuit for the \overline{OC} Pin

Power Dissipation and Junction Temperature

The low on-resistance on the N-channel MOSFET allows the small surface-mount packages to pass large currents. The thermal resistances of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the $r_{DS(on)}$ of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $r_{DS(on)}$ from [Figure 17](#). Using this value, the power dissipation per switch can be calculated by:

$$P_D = r_{DS(on)} \times I^2$$

Multiply this number by the number of switches being used. This step renders the total power dissipation from the N-channel MOSFETs.

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

T_A = Ambient temperature ($^{\circ}\text{C}$)

$R_{\theta JA}$ = Thermal resistance

P_D = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

Thermal Protection

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The TPS2041B implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises due to excessive power dissipation. Once the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 10°C , the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The \overline{OC} open-drain output is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

Undervoltage Lockout (UVLO)

The UVLO ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO also keeps the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. On reinsertion, the power switch is turned on, with a controlled rise time to reduce EMI and voltage overshoots.

Universal Serial Bus (USB) Applications

The universal serial bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.

The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPHs)
- Bus-powered hubs (BPHs)
- Low-power bus-powered functions
- High-power bus-powered functions
- Self-powered functions

Self-powered and bus-powered hubs distribute data and power to downstream functions. The TPS2041B can provide power-distribution solutions to many of these classes of devices.

Hosts/Self-Powered Hubs and Bus-Powered Hubs

Hosts and self-powered hubs have a local power supply that powers the embedded functions and the downstream ports (see Figure 24). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.

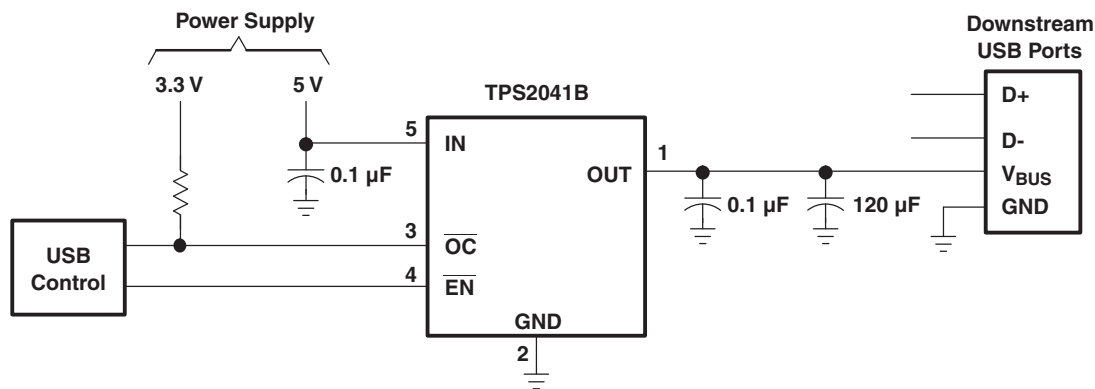


Figure 24. Typical One-Port USB Host/Self-Powered Hub

Bus-powered hubs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.

Low-Power and High-Power Bus-Powered Functions

Both low-power and high-power bus-powered functions obtain all power from upstream ports; low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of 44 Ω and 10 μF at power up, the device must implement inrush current limiting (see [Figure 25](#)).

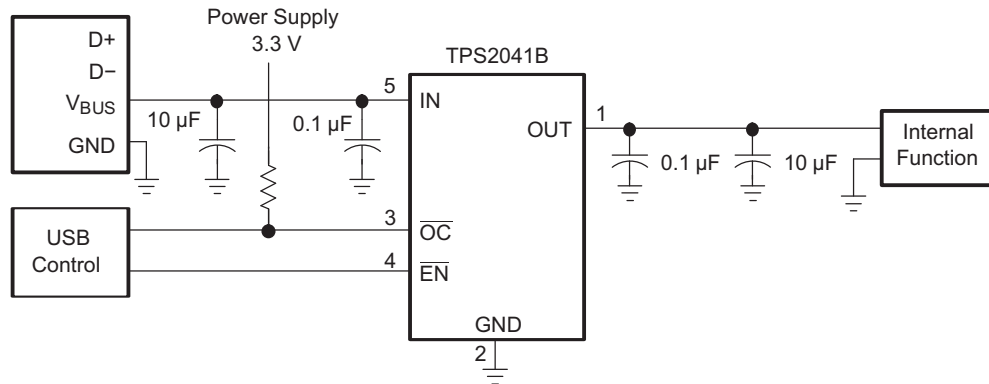


Figure 25. High-Power Bus-Powered Function

USB Power-Distribution Requirements

USB can be implemented in several ways, and, regardless of the type of USB device being developed, several power-distribution features must be implemented.

- Hosts/self-powered hubs must:
 - Current-limit downstream ports
 - Report overcurrent conditions on USB V_{BUS}
- Bus-powered hubs must:
 - Enable/disable power to downstream ports
 - Power up at <100 mA
 - Limit inrush current (<44 Ω and 10 μF)
- Functions must:
 - Limit inrush currents
 - Power up at <100 mA

The feature set of the TPS2041B allows them to meet each of these requirements. The integrated current-limiting and overcurrent reporting is required by hosts and self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-powered hubs, as well as the input ports for bus-powered functions (see [Figure 26](#)).

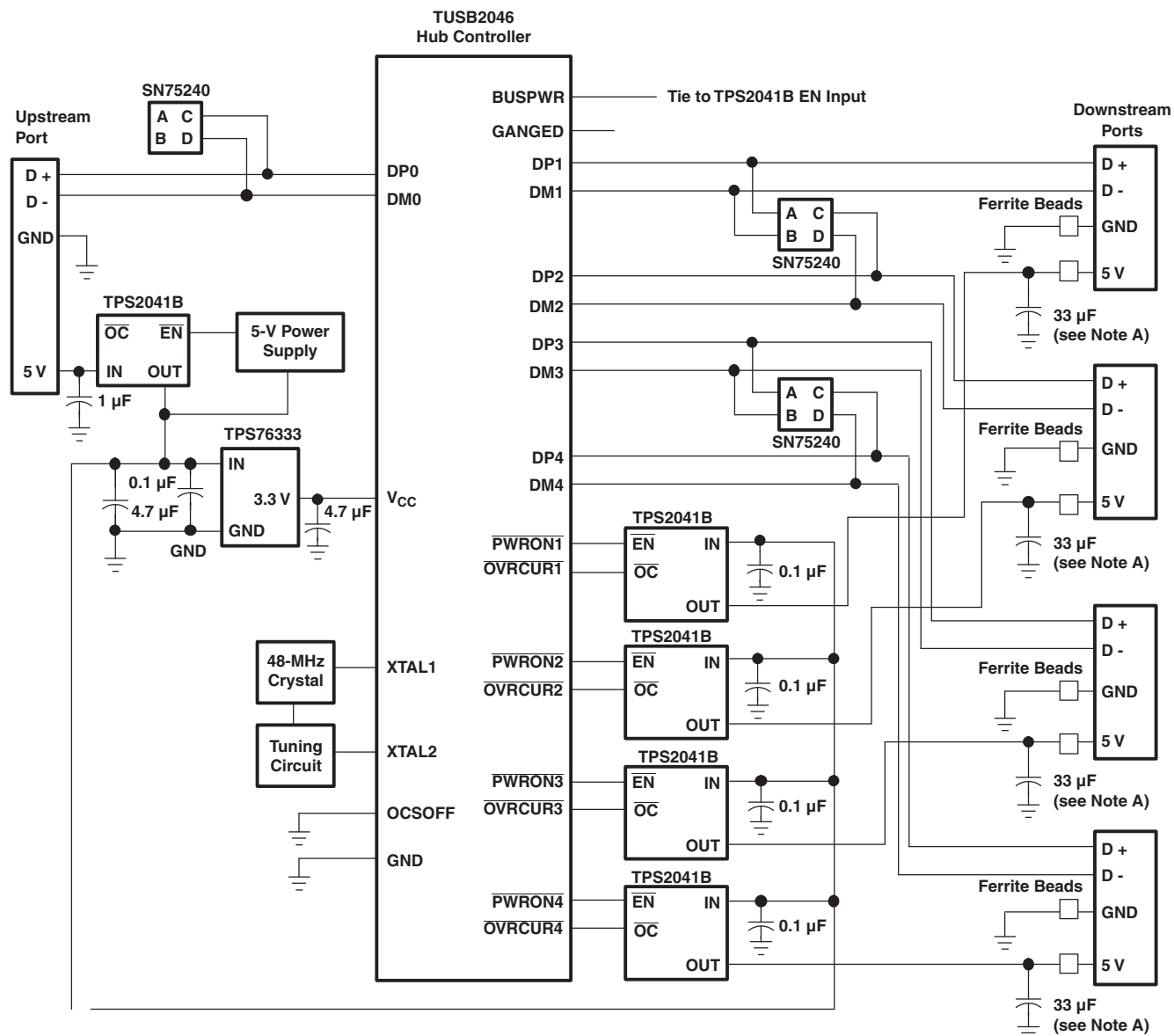


Figure 26. Hybrid Self-Powered/Bus-Powered Hub Implementation

Generic Hot-Plug Applications

In many applications, it may be necessary to remove modules or PC boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS2041B, these devices can be used to provide a softer startup to devices being hot-plugged into a powered system. The UVLO feature of the TPS2041B also ensures that the switch is off after the card has been removed, and that the switch is off during the next insertion. The UVLO feature ensures a soft start with a controlled rise time for every insertion of the card or module.

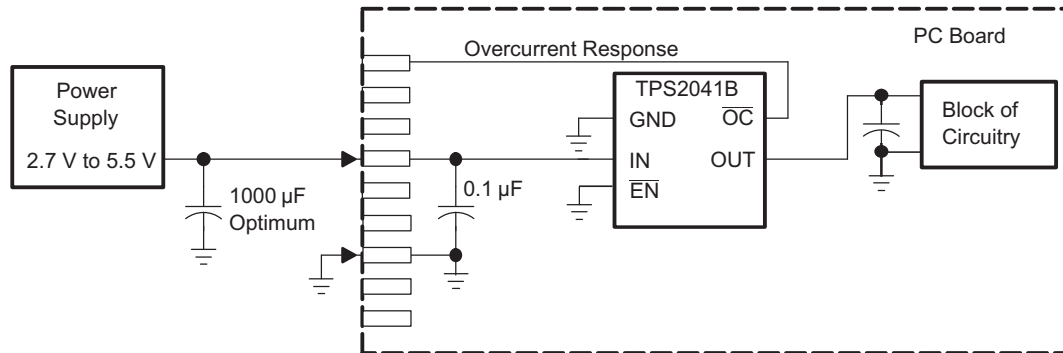


Figure 27. Typical Hot-Plug Implementation

By placing the TPS2041B between the V_{CC} input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

DETAILED DESCRIPTION

Power Switch

The power switch is an N-channel MOSFET with a low on-state resistance. Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum current of 500 mA.

Charge Pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires little supply current.

Driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

Enable (\overline{EN})

The logic enable pin disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current. The supply current is reduced to less than 1 μ A or 2 μ A when a logic high is present on \overline{EN} . A logic zero input on \overline{EN} restores bias to the drive and control circuits and turns the switch on. The enable input is compatible with both TTL and CMOS logic levels.

Overcurrent (\overline{OC})

The \overline{OC} open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output remains asserted until the overcurrent or overtemperature condition is removed. A 10-ms deglitch circuit prevents the \overline{OC} signal from oscillation or false triggering. If an overtemperature shutdown occurs, the \overline{OC} is asserted instantaneously.

Current Sense

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

Thermal Sense

The TPS2041B implements a thermal sensing to monitor the operating temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises. When the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns off the switch, thus preventing the device from damage. Hysteresis is built into the thermal sense, and after the device has cooled approximately 10 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The open-drain false reporting output (\overline{OC}) is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

Undervoltage Lockout (UVLO)

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS2041BMDVBTEP	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	PXAM
TPS2041BMDVBTEP.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	PXAM
V62/11620-01XE	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	PXAM

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS2041B-EP :

- Catalog : [TPS2041B](#)

- Automotive : [TPS2041B-Q1](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2041BMDVBTEP	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2041BMDBVTEP	SOT-23	DBV	5	250	180.0	180.0	18.0



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

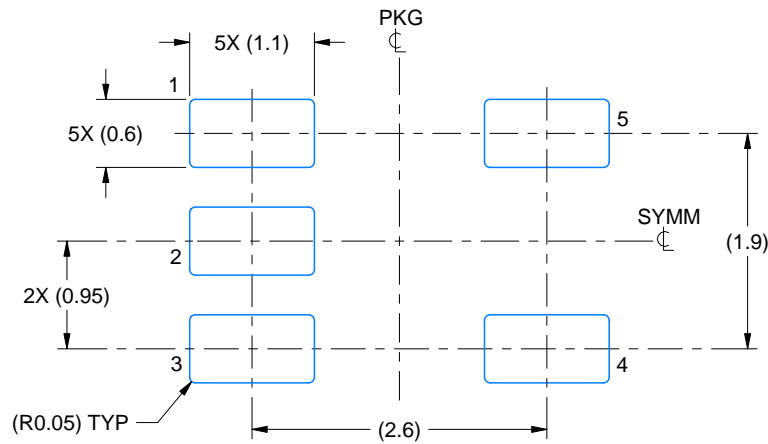


1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

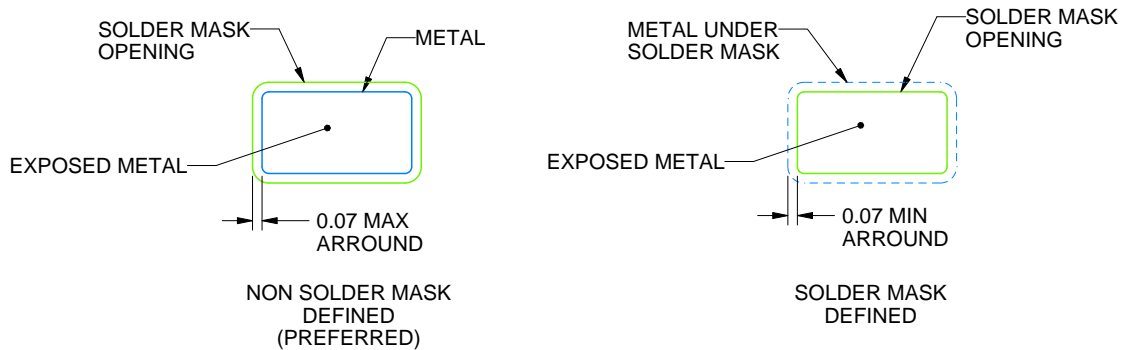
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025